## **SFB 608**

## Einladung zum Kolloquium

Ort: Universität zu Köln

II. Physikalisches Institut, Seminarraum 201

**Zeit:** Mittwoch, 23.07.03, 15 Uhr c.t.

**Sprecher:** Professor S.G. Ovchinnikov

Kirenskii Institute of Physics, Russian Academy of Sciences,

Krasnoyarsk (Siberia), Russia

Thema: The electronic energy structure of FeBO<sub>3</sub> and its change

under high pressure in the multi-electron approach taking into account strong electron correlations

## Abstract of the talk:

A multi-electron model of the electronic structure for FeBO<sub>3</sub> is presented. The bottom of the conductivity band and the top of the valence band are formed by s,p electrons of the BO<sub>3</sub> group, and in the wide energy gap there are d-levels of 3d-ion. These levels are calculated as d-resonances between the multi-electron terms of d(n) configurations. Local d-resonances  $E(d^6)$ - $E(d^5)$  and  $E(d^5)$ - $E(d^4)$  are calculated resulting in adding and removing one d-electron to Fe<sup>+3</sup> ion, and the scheme of the density of states is constructed in good agreement to optical absorption spectra. According to this scheme FeBO<sub>3</sub> is a charge-transfer insulator. Under external pressure the crystal field parameter 10Dq increases, and at some critical value the crossover of high-spin 5/2 to low-spin 1/2 takes place. In the high-pressure phase the change of the energy level scheme results in a smaller value of the semiconducting energy gap. The magnetic properties of the high-pressure phase are predicted to be antiferromagnet with S=1/2 and a low Neel temperature.